# JYJE 8208 Ultra Performance Oscillator



#### **Features**

- Any frequency between 1 and 80 MHz accurate to 6 decimal places
- 100% pin-to-pin drop-in replacement to quartz-based oscillators
- Ultra low phase jitter: 0.5 ps (12 kHz to 20 MHz)
- Frequency stability as low as ±10 PPM
- Industrial or extended commercial temperature range
- LVCMOS/LVTTL compatible output
- Standard 4-pin packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm x mm
- Instant samples with Time Machine II and field programmable oscillators
- Outstanding silicon reliability of 2 FIT or 500 million hour MTBF
- Pb-free, RoHS and REACH compliant
- Ultra short lead time

### **Applications**

- SATA, SAS, Ethernet, PCI Express, video, WiFi
- Computing, storage, networking, telecom, industrial control

# Electrical Characteristics<sup>[1]</sup>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
			F	requency R	lange	
Output Frequency Range	f	1	_	80	MHz	
			Freque	ncy Stability	and Aging	9
Frequency Stability	F_stab	-10	_	+10	PPM	Inclusive of Initial tolerance at 25 °C, and variations over
		-20	_	+20	PPM	operating temperature, rated power supply voltage and load
		-25	-	+25	PPM	
		-50	_	+50	PPM	
First year Aging	F_aging	-1.5	-	+1.5	PPM	25°C
10-year Aging		-5	_	+5	PPM	25°C
			Operati	ng Tempera	ature Range	е
Operating Temperature Range	T_use	-20	-	+70	°C	Extended Commercial
		-40	-	+85	°C	Industrial
		S	upply Volta	ge and Curr	ent Consu	mption
Supply Voltage	Vdd	1.71	1.8	1.89	V	Supply voltages between 2.5V and 3.3V can be supported.
		2.25	2.5	2.75	V	Contact JYJE for additional information.
		2.52	2.8	3.08	V	
		2.97	3.3	3.63	V	
Current Consumption	ldd	_	31	33	mA	No load condition, f = 20 MHz, Vdd = 2.5V, 2.8V or 3.3V
		_	29	31	mA	No load condition, f = 20 MHz, Vdd = 1.8V
OE Disable Current	I_OD	-	_	31	mA	Vdd = 2.5V, 2.8V or 3.3V, OE = GND, output is Weakly Pulled Down
		_	-	30	mA	Vdd = 1.8 V. OE = GND, output is Weakly Pulled Down
Standby Current	I_std	_	_	70	μА	Vdd = 2.5V, 2.8V or 3.3V, ST = GND, output is Weakly Pulled Down
		-	-	10	μА	Vdd = 1.8 V. ST = GND, output is Weakly Pulled Down
			LVCMOS	Output Ch	aracteristic	cs
Duty Cycle	DC	45	-	55	%	
Rise/Fall Time	Tr, Tf	-	1.2	2	ns	15 pF load, 10% - 90% Vdd
Output Voltage High	VOH	90%	-	-	Vdd	IOH = -6 mA, IOL = 6 mA, (Vdd = 3.3V, 2.8V, 2.5V)
Output Voltage Low	VOL	_	-	10%	Vdd	IOH = -3 mA, IOL = 3 mA, (Vdd = 1.8V)
			Inp	out Characte	eristics	
Input Voltage High	VIH	70%	_	_	Vdd	Pin 1, OE or ST
Input Voltage Low	VIL	-	-	30%	Vdd	Pin 1, OE or ST
Input Pull-up Impedance	Z_in	-	100	250	kΩ	Pin 1, OE logic high or logic low, or ST logic high
		2	_	_	MΩ	Pin 1, ST logic low

#### Note:

<sup>1.</sup> All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.

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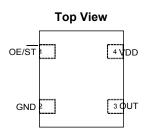
# Electrical Characteristics<sup>[1]</sup> (Continued)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Startup and Resume Timing							
Startup Time	T_start	_	7	10	ms	Measured from the time Vdd reaches its rated minimum value	
OE Enable/Disable Time	T_oe	_	_	150	ns	f = 80 MHz, For other frequencies, T_oe = 100 ns + 3 cycles	
Resume Time	T_resume	-	6	10	ms	In standby mode, measured from the time $\overline{\text{ST}}$ pin crosses 50% threshold. Refer to Figure 5.	
				Jitter			
RMS Period Jitter	T_jitt	_	1.5	2	ps		
		-	2	3	ps	f = 75 MHz, Vdd = 1.8V	
RMS Phase Jitter (random)	T_phj	-	0.5	1	ps	f = 10 MHz, Integration bandwidth = 12 kHz to 20 MHz	

#### Note:

## **Pin Configuration**

Pin	Symbol	Functionality			
		Output Enable	H or Open <sup>[2]</sup> : specified frequency output L: output is high impedance. Only output driver is disabled.		
1	1 OE/ ST Standby		H or Open <sup>[2]</sup> : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.		
2	GND	Power	Electrical ground <sup>[3]</sup>		
3	OUT	Output	Oscillator output		
4	VDD	Power	Power supply voltage <sup>[3]</sup>		



#### Notes:

- 2. A pull-up resistor of <10 k $\Omega$  between OE/  $\overline{ST}$  pin and Vdd is recommended in high noise environment.
- 3. A capacitor of value 0.1  $\mu\text{F}$  between Vdd and GND is recommended.

#### **Absolute Maximum**

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	-	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	-	260	°C
Junction Temperature	-	150	°C

#### **Thermal Consideration**

Package	θJA, 4 Layer Board (°C/W)	θJA, 2 Layer Board (°C/W)	θJC, Bottom (°C/W)
7050	191	263	30
5032	97	199	24
3225	109	212	27
2520	117	222	26

## **Environmental Compliance**

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

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<sup>1.</sup> All electrical specifications in the above table are specified with 15 pF output load and for all Vdd(s) unless otherwise stated.



#### **Phase Noise Plot**

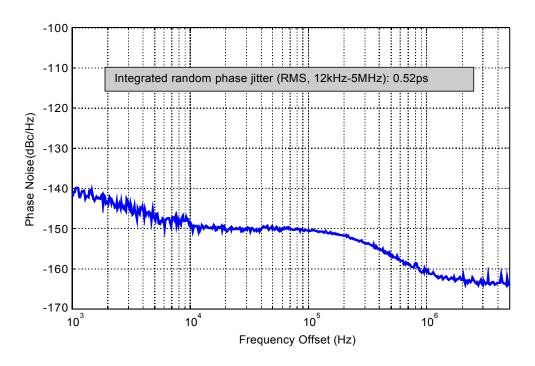
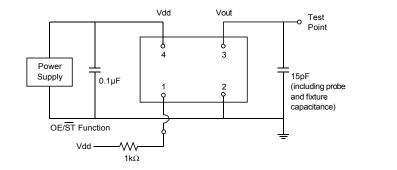


Figure 1. Phase Noise, 10 MHz, 3.3V, LVCMOS Output

#### **Test Circuit and Waveform**



tr — tf

90% Vdd
50%
10% Vdd

High Pulse
(TH)

Period

Period

Figure 2. Test Circuit

Figure 3. Waveform

#### Notes:

4. Duty Cycle is computed as Duty Cycle = TH/Period.

5. JYJE8208 supports the configurable duty cycle feature. For custom duty cycle at any given frequency, contact JYJE.

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## **Timing Diagram**

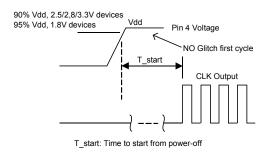


Figure 4. Startup Timing (OE/ST Mode)

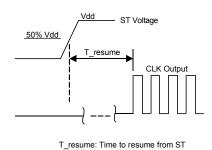
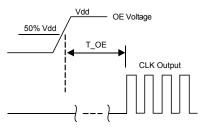
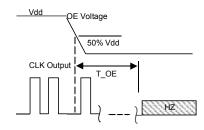


Figure 5. Standby Resume Timing (ST Mode Only)



T\_OE: Time to re-enable the clock output



T\_OE: Time to put the output drive in High Z mode

Figure 6. OE Enable Timing (OE Mode Only)

Figure 7. OE Disable Timing (OE Mode Only)

#### Notes:

- 6. JYJE8208 supports NO RUNT pulses and No glitches during startup or resume.
- 7. JYJE8208 supports gated output which is accurate within rated frequency stability from the first cycle.

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#### **Performance Plots**

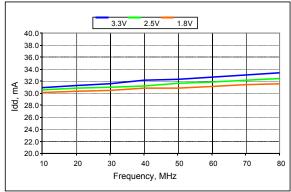


Figure 8. Idd vs Frequency

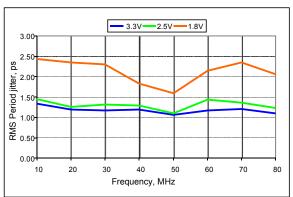


Figure 9. RMS Period Jitter vs Frequency

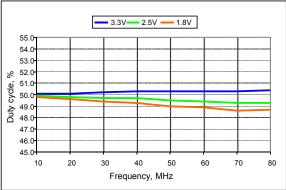


Figure 10. Duty Cycle vs Frequency

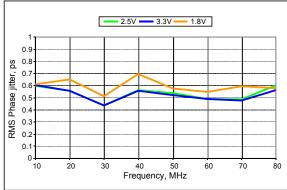


Figure 11. RMS Phase Jitter vs Frequency

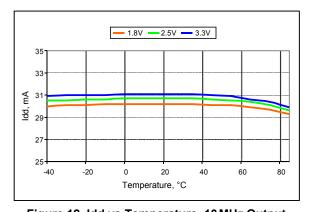


Figure 12. Idd vs Temperature, 10 MHz Output

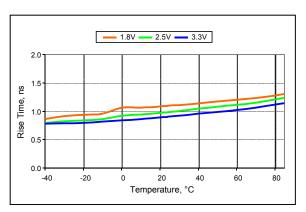


Figure 13. Rise Time vs Temperature, 75 MHz Output

#### Note:

8. All plots are measured with 15 pF load at room temperature, unless otherwise stated.

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# **JYJE 8208**

#### **Ultra Performance Oscillator**



#### **Programmable Drive Strength**

The JYJE8208 includes a programmable drive strength feature to provide a simple, flexible tool to optimize the clock rise/fall time for specific applications. Benefits from the programmable drive strength feature are:

- Improves system radiated electromagneticinterference (EMI) by slowing down the clock rise/fall time
- Improves the downstream clock receiver's (RX) jitter by decreasing (speeding up) the clock rise/fall time.
- Ability to drive large capacitive loads while maintaining full swing with sharp edge rates.

#### **EMI Reduction by Slowing Rise/Fall Time**

Figure 14 shows the harmonic power reduction as the rise/fall times are increased (slowed down). The rise/fall times are expressed as a ratio of the clock period. For the ratio of 0.05, the signal is very close to a square wave. For the ratio of 0.45, the rise/fall times are very close to near-triangular waveform. These results, for example, show that the 11th clock harmonic can be reduced by 35 dB if the rise/fall edge is increased from 5% of the period to 45% of the period.

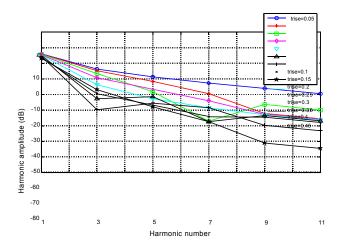


Figure 14. Harmonic EMI reduction as a Function of Slower Rise/Fall Time

#### Jitter Reduction with Faster Rise/Fall Time

Power supply noise can be a source of jitter for the downstream chipset. One way to reduce this jitter is to increase rise/fall time (edge rate) of the input clock. Some chipsets would require faster rise/fall time in order to reduce their sensitivity to this type of jitter. The JYJE8208 provides up to 3 additional high drive strength settings for very fast rise/fall time. Refer to the Rise/Fall Time Tables to determine the proper drive strength.

#### **High Output Load Capability**

The rise/fall time of the input clock varies as a function of the actual capacitive load the clock drives. At any given drive strength, the rise/fall time becomes slower as the output load increases. As an example, for a 3.3V JYJE8208 device with default drive strength setting, the typical rise/fall time is 1.15ns for 15 pF output load. The typical rise/fall time slows down to 2.72ns when the output load increases to 45 pF. One can

choose to speed up the rise/fall time to 1.41ns by then increasing the drive strength setting on the JYJE8208.

The JYJE8208 can support up to 60 pF or higher in maximum capacitive loads with up to 3 additional drive strength settings. Refer to the Rise/Tall Time Tables to determine the proper drive strength for the desired combination of output load vs. rise/fall time

#### JYJE8208 Drive Strength Selection

Tables 1 through 5 define the rise/fall time for a given capacitive load and supply voltage.

- 1. Select the table that matches the JYJE8208 nominal supply voltage (1.8V, 2.5V, 2.8V, 3.0V, 3.3V).
- Select the capacitive load column that matches the application requirement (5 pF to 60 pF)
- 3. Under the capacitive load column, select the desired rise/fall times.
- The left-most column represents the part number code for the corresponding drive strength.
- 5. Add the drive strength code to the part number for ordering purposes.

#### **Calculating Maximum Frequency**

Based on the rise and fall time data given in Tables 1 through 4, the maximum frequency the oscillator can operate with guaranteed full swing of the output voltage over temperature as follows:

Max Frequency = 
$$\frac{1}{6 \times (Trise)}$$

#### Example 1

Calculate f<sub>MAX</sub> for the following condition:

- Vdd = 1.8V (Table 1)
- · Capacitive Load: 30 pF
- Desired Tr/f time = 3 ns (rise/fall time part number code = G)

Part number for the above example:

JYJE8208AIGG2-18E-55.500000



Drive strength code is inserted here. Default setting is "-"

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# Rise/Fall Time (10% to 90%) vs $C_{LOAD}$ Tables

	Rise/Fall Time Typ (ns)					
Drive Strength \ C <sub>LOAD</sub>	5 pF	15 pF	30 pF	45 pF	60 pF	
L	12.45	17.68	19.48	46.21	57.82	
Α	6.50	10.27	16.21	23.92	30.73	
R	4.38	7.05	11.61	16.17	20.83	
В	3.27	5.30	8.89	12.18	15.75	
S	2.62	4.25	7.20	9.81	12.65	
D	2.19	3.52	6.00	8.31	10.59	
T	1.76	3.01	5.14	7.10	9.15	
E	1.59	2.59	4.49	6.25	7.98	
U	1.49	2.28	3.96	5.55	7.15	
F	1.22	2.10	3.57	5.00	6.46	
W	1.07	1.88	3.23	4.50	5.87	
G	1.01	1.64	2.95	4.12	5.40	
Х	0.96	1.50	2.74	3.80	4.98	
K	0.92	1.41	2.56	3.52	4.64	
Υ	0.88	1.34	2.39	3.25	4.32	
Q	0.86	1.29	2.24	3.04	4.06	
Z or "-": Default	0.82	1.24	2.07	2.89	3.82	
М	0.77	1.20	1.94	2.72	3.61	
N	0.66	1.15	1.84	2.58	3.41	
Р	0.51	1.09	1.76	2.45	3.24	

Table 1. Vdd = 1.8V Rise/Fall Times for Specific C<sub>LOAD</sub>

Rise/Fall Time Typ (ns)					
Drive Strength \ C <sub>LOAD</sub>	5 pF	15 pF	30 pF	45 pF	60 pF
L	7.93	12.69	17.94	30.10	38.89
Α	4.06	6.66	11.04	15.31	19.80
R	2.68	4.40	7.53	10.29	13.37
В	2.00	3.25	5.66	7.84	10.11
S	1.59	2.57	4.54	6.27	8.07
D	1.19	2.14	3.76	5.21	6.72
Т	1.00	1.79	3.20	4.43	5.77
E	0.94	1.51	2.78	3.84	5.06
U	0.90	1.38	2.48	3.40	4.50
F	0.87	1.29	2.21	3.03	4.05
W	0.62	1.19	1.99	2.76	3.68
G or "-": Default	0.41	1.08	1.84	2.52	3.36
X	0.37	0.96	1.72	2.33	3.15
K	0.35	0.78	1.63	2.15	2.92
Υ	0.33	0.67	1.54	2.00	2.75
Q	0.32	0.63	1.46	1.89	2.57
Z	0.31	0.60	1.39	1.80	2.43
M	0.30	0.57	1.31	1.72	2.30
N	0.30	0.56	1.22	1.63	2.22
Р	0.29	0.54	1.13	1.55	2.13

Table 3. Vdd = 2.8V Rise/Fall Times for Specific C<sub>LOAD</sub>

Rise/Fall Time Typ (ns)					
Drive Strength \ C <sub>LOAD</sub>	5 pF	15 pF	30 pF	45 pF	60 pF
L	8.68	13.59	18.36	32.70	42.06
Α	4.42	7.18	11.93	16.60	21.38
R	2.93	4.78	8.15	11.19	14.59
В	2.21	3.57	6.19	8.55	11.04
S	1.67	2.87	4.94	6.85	8.80
D	1.50	2.33	4.11	5.68	7.33
Т	1.06	2.04	3.50	4.84	6.26
Ш	0.98	1.69	3.03	4.20	5.51
U	0.93	1.48	2.69	3.73	4.92
F	0.90	1.37	2.44	3.34	4.42
W	0.87	1.29	2.21	3.04	4.02
G or "-": Default	0.67	1.20	2.00	2.79	3.69
X	0.44	1.10	1.86	2.56	3.43
K	0.38	0.99	1.76	2.37	3.18
Υ	0.36	0.83	1.66	2.20	2.98
Q	0.34	0.71	1.58	2.07	2.80
Z	0.33	0.65	1.51	1.95	2.65
M	0.32	0.62	1.44	1.85	2.50
N	0.31	0.59	1.37	1.77	2.39
Р	0.30	0.57	1.29	1.70	2.28

Table 2. Vdd = 2.5V Rise/Fall Times for Specific C<sub>LOAD</sub>

Rise/Fall Time Typ (ns)					
Drive Strength \ C <sub>LOAD</sub>	5 pF	15 pF	30 pF	45 pF	60 pF
L	7.18	11.59	17.24	27.57	35.57
Α	3.61	6.02	10.19	13.98	18.10
R	2.31	3.95	6.88	9.42	12.24
В	1.65	2.92	5.12	7.10	9.17
S	1.43	2.26	4.09	5.66	7.34
D	1.01	1.91	3.38	4.69	6.14
T	0.94	1.51	2.86	3.97	5.25
E	0.90	1.36	2.50	3.46	4.58
U	0.86	1.25	2.21	3.03	4.07
F or "-": Default	0.48	1.15	1.95	2.72	3.65
W	0.38	1.04	1.77	2.47	3.31
G	0.36	0.87	1.66	2.23	3.03
X	0.34	0.70	1.56	2.04	2.80
K	0.33	0.63	1.48	1.89	2.61
Υ	0.32	0.60	1.40	1.79	2.43
Q	0.32	0.58	1.31	1.69	2.28
Z	0.30	0.56	1.22	1.62	2.17
М	0.30	0.55	1.12	1.54	2.07
N	0.30	0.54	1.02	1.47	1.97
Р	0.29	0.52	0.95	1.41	1.90

Table 4. Vdd = 3.3V Rise/Fall Times for Specific C<sub>LOAD</sub>

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# JYJE 8208 Ultra Performance Oscillator



# Instant Samples with Time Machine and Field Programmable Oscillators

JYJE supports a field programmable version of the JYJE8208 low power oscillator for fast prototyping and real time customization of features. The <u>field programmable devices</u> (FP devices) are available for all five standard JYJE8208 package sizes and can be configured to one's exact specification using the <u>Time Machine II</u>, an USB powered MEMS oscillator programmer.

**Customizable Features of the JYJE8208 FP Devices Include** 

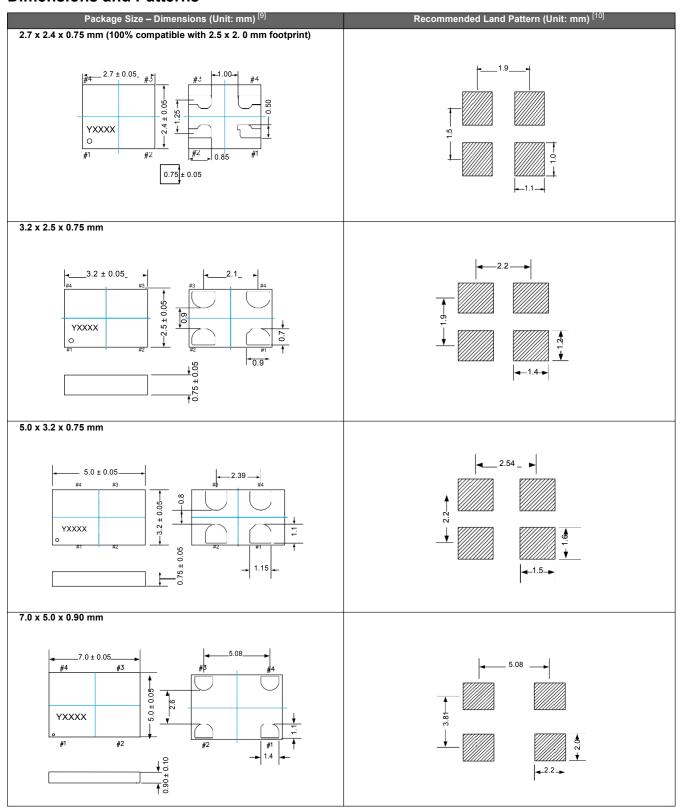
- Any frequency between 1 110 MHz
- Three frequency stability options, ±20 PPM, ±25 PPM, ±50 PPM
- Two operating temperatures, -20 to 70°C or -40 to 85°C
- Five supply voltage options, 1.8V, 2.5V, 2.8V, 3.0V, and 3.3V
- · Output drive strength

JYJE8208 is typically factory-programmed per customer ordering codes for volume delivery.

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#### **Dimensions and Patterns**



9. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

10. A capacitor of value 0.1 µF between Vdd and GND is recommended.

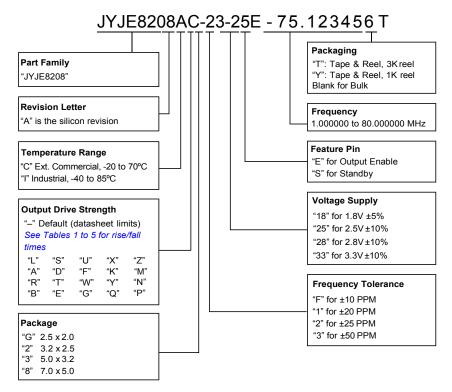
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# **Silicon MEMS Outperforms Quartz**



#### **Ordering Information**

The Part No. Guide is for reference only. To customize and build an exact part number, use the JYJE <a href="Part Number generator">Part Number generator</a>.



#### **Additional Information**

Document	Description
Time Machine II	MEMS oscillator programmer
Field Programmable Oscillators	Devices that can be programmable in the field by Time Machine II
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info
Qualification Reports	RoHS report, reliability reports, composition reports
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies
Termination Techniques	Termination design recommendations
Layout Techniques	Layout recommendations

# **Silicon MEMS Outperforms Quartz**



#### **Best Reliability**

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, JYJE has in-house MEMS and analog CMOS expertise, which allows JYJE to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

#### Why is JYJE Best in Class:

- JYJE's MEMS resonators are vacuum sealed using an advanced Epi-Seal™ process, which eliminates foreign particles and improves long term aging and reliability
- · World-class MEMS and CMOS design expertise

#### **Best Aging**

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new JYJE product specifies 10-year aging A comparison is shown in Figure 2.

#### Why is SiTime Best in Class:

- JYJE's MEMS resonators are vacuum sealed using an advanced Epi-Seal™ process, which eliminates foreign particles and improves long term aging and reliability
- · Inherently better immunity of electrostatically driven MEMS resonator

# **Silicon MEMS Outperforms Quartz**



#### **Best Electro Magnetic Susceptibility (EMS)**

JYJE's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

#### Why is JYJE Best in Class:

- · Internal differential architecture forbest common mode noise rejection
- · Electrostatically driven MEMS resonator is more immune to EMS

#### **Best Power Supply Noise Rejection**

JYJE's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

#### Why is JYJE Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- · Best analog CMOS design experti

#### **Best Vibration Robustness**

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

#### Why is JYJE Best in Class:

- The moving mass of JYJE's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the mostrobust design
- Notes:
- 1. Data Source: Reliability documents of named companies.
- 2. Data source: JYJE and quartz oscillator devices datasheets.
- 3. Test conditions for Electro Magnetic Susceptibility (EMS):
  - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
  - · Field strength: 3V/m
  - Radiated signal modulation: AM 1 kHz at 80% depth
  - Carrier frequency scan: 80 MHz 1 GHz in 1% steps
  - · Antenna polarization: Vertical
  - DUT position: Center aligned to antenna

#### Devices used in this test:

JYJE, JYJE9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz

Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz

TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz

Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz

Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz

SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz

4. 50 mV pk-pk Sinusoidal voltage.

#### Devices used in this test:

JYJE, JYJE8208AI-33-33E-25.000000, MEMS based - 25 MHz

NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz

Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz

Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz

- 5. Devices used in this test: same as EMS test stated in Note 3.
- 6. Test conditions for shock test:
  - MIL-STD-883F Method 2002
  - Condition A: half sine wave shock pulse, 500-g, 1ms
  - $\bullet$  Continuous frequency measurement in 100  $\mu s$  gate time for 10 seconds

Devices used in this test: same as EMS test stated in Note 3

7. Additional data, including setup and detailed results, is available upon request to qualified customers.